

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3098138	memory or storage	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/02 10:27
L2	130058	1 and (resist\$5 or mram or magnetic) with (cell or element)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/02 10:28
L3	2741	2 and select\$5 adj2 (transistor or element) with cell	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/02 10:29
L4	183	3 and end with (cell or element) with (common or together)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/02 10:33
L5	23	4 and (local or global) with (bit or bitline or digit)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/02 10:30
L6	16	4 and equaliz\$5 with (bit or bitline)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/02 10:33